

High- and Low-Side Gate Driver

FAN7842

Description

The FAN7842, a monolithic high and low side gate drive IC, which can drive MOSFETs and IGBTs that operate up to +200 V.

onsemi's high–voltage process and common–mode noise canceling technique provide stable operation of the high–side driver under high–dv/dt noise circumstances. An advanced level–shift circuit allows high–side gate driver operation up to $V_S = -9.8\ V$ (typical) for $V_{BS} = 15\ V$. The input logic level is compatible with standard TTL–series logic gates.

The UVLO circuits for both channels prevent malfunction when V_{CC} and V_{BS} are lower than the specified threshold voltage. Output driver current (source/sink) is typically 350 mA/650 mA, respectively.

Features

- Floating Channels Designed for Bootstrap Operation to +200 V
- Typically 350 mA/650 mA Sourcing/Sinking Current Driving Capability for Both Channels
- Common-Mode dv/dt Noise Canceling Circuit
- Extended Allowable Negative V_S Swing to -9.8 V for Signal Propagation at $V_{CC} = V_{BS} = 15$ V
- V_{CC} & V_{BS} Supply Range from 10 V to 20 V
- UVLO Functions for Both Channels
- TTL Compatible Input Logic Threshold Levels
- Matched Propagation Delay Below 50 ns
- Output In-phase with Input Signal
- This Device is Pb-Free, Halide Free and is RoHS Compliant

Applications

- Battery Based Motor Applications (E-bike, Power Tool)
- Telecom DC-DC Converter

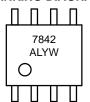
Related Resources

- <u>AN-6076</u> Design and Application Guide of Bootstrap Circuit for High–Voltage Gate–Drive IC
- AN-9052 Design Guide for Selection of Bootstrap Components
- <u>AN-8102</u> Recommendations to Avoid Short Pulse Width Issues in HVIC Gate Driver Applications

1



MARKING DIAGRAM



7842 = Specific Device Code
A = Assembly Site
L = Wafer Lot Number
YW = Assembly Start Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.

TYPICAL APPLICATION CIRCUIT

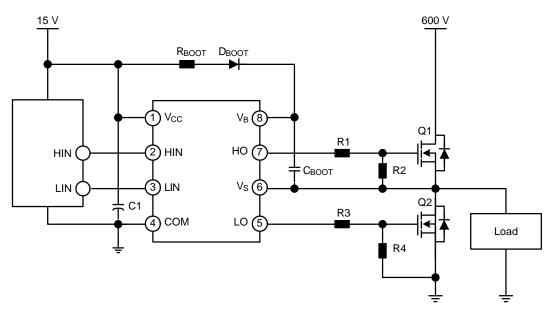


Figure 1. Application Circuit for Half-Bridge

INTERNAL BLOCK DIAGRAM

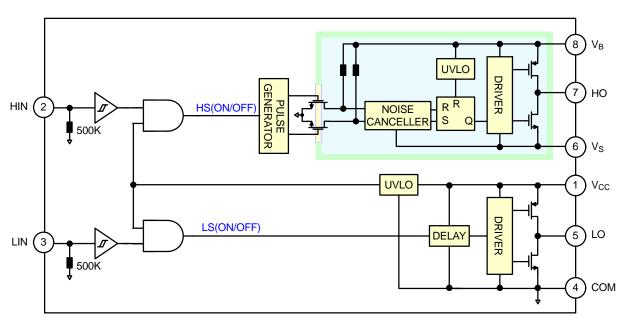


Figure 2. Functional Block Diagram

PIN ASSIGNMENTS

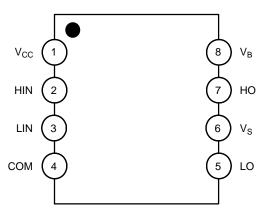


Figure 3. Pin Configuration (Top View)

PIN DEFINITIONS

Name	Description	
V _{CC}	Low-Side Supply Voltage	
HIN	Logic Input for High-Side Gate Driver Output	
LIN	Logic Input for Low-Side Gate Driver Output	
СОМ	Logic Ground and Low–Side Driver Return	
LO	Low-Side Driver Output	
Vs	High-Voltage Floating Supply Return	
НО	High-Side Driver Output	
V _B	High–Side Floating Supply	

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Min	Max	Unit
V _S	High-side Offset Voltage	V _B – 25	V _B + 0.3	V
V _B	High-side Floating Supply Voltage	-0.3	225	
V _{HO}	High-side Floating Output Voltage HO	V _S - 0.3	V _B + 0.3	
V _{CC}	Low-side and Logic Fixed Supply Voltage	-0.3	25	
V_{LO}	Low-side Output Voltage LO	-0.3	V _{CC} + 0.3	
V _{IN}	Logic Input Voltage (HIN, LIN)	-0.3	V _{CC} + 0.3	
СОМ	Logic Ground	V _{CC} – 25	V _{CC} + 0.3	
dV _S /dt	Allowable Offset Voltage Slew Rate	-	50	V/ns
P _D (Note 1) (Note 2) (Note 3)	Power Dissipation	-	0.625	W
θ_{JA}	Thermal Resistance, Junction-to-ambient	-	200	°C/W
TJ	Junction Temperature	-	150	°C
T _{STG}	Storage Temperature	-	150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Mounted on 76.2 x 114.3 x 1.6 mm PCB (FR–4 glass epoxy material).

- 2. Refer to the following standards:
 - JESD51–2: Integral circuits thermal test method environmental conditions natural convection JESD51-3: Low effective thermal conductivity test board for leaded surface mount packages
- 3. Do not exceed P_D under any circumstances.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _B	High-side Floating Supply Voltage	V _S + 10	V _S + 20	V
Vs	High-side Floating Supply Offset Voltage	6 – V _{CC}	200	
V _{HO}	High-side (HO) Output Voltage	V _S	V _B	
V_{LO}	Low-side (LO) Output Voltage	СОМ	V _{CC}	
V _{IN}	Logic Input Voltage (HIN, LIN)	СОМ	V _{CC}	
V _{CC}	Low-side Supply Voltage	10	20	
T _A	Ambient Temperature	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS (V_{BIAS} (V_{CC} , V_{BS}) = 15.0 V, T_A = 25°C, unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to V_S and COM and are applicable to the respective outputs HO and LO.)

Symbol	Characteristics	Test Condition	Min	Тур	Max	Unit
V _{CCUV+} V _{BSUV+}	V _{CC} and V _{BS} Supply Under–voltage Positive Going Threshold		8.2	9.2	10.0	V
V _{CCUV} - V _{BSUV} -	V _{CC} and V _{BS} Supply Under–voltage Negative Going Threshold		7.6	8.7	9.6	
V _{CCUVH} V _{BSUVH}	V _{CC} Supply Under–voltage Lockout Hysteresis		-	0.6	-	
I _{LK}	Offset Supply Leakage Current	V _B = V _S = 200 V	-	-	50	μΑ
I_{QBS}	Quiescent V _{BS} Supply Current	V _{IN} = 0 V or 5 V	-	45	120	1
I _{QCC}	Quiescent V _{CC} Supply Current	V _{IN} = 0 V or 5 V	-	70	180	1
I _{PBS}	Operating V _{BS} Supply Current	f _{IN} = 20 kHz, rms value	-	-	600	μΑ
I _{PCC}	Operating V _{CC} Supply Current	f _{IN} = 20 kHz, rms value	-	-	600	1
V_{IH}	Logic "1" Input Voltage		2.9	-	_	V
V_{IL}	Logic "0" Input Voltage		-	-	0.8	
V _{OH}	High-level Output Voltage, V _{BIAS} -V _O	I _O = 20 mA	-	-	1.0	
V _{OL}	Low-level Output Voltage, VO		-	-	0.6	
I _{IN+}	Logic "1" Input Bias Current	V _{IN} = 5 V	-	10	20	μΑ
I _{IN} _	Logic "0" Input Bias Current	V _{IN} = 0 V	-	1.0	2.0	
I _{O+}	Output High Short-circuit Pulsed Current	$V_O = 0 \text{ V}, V_{IN} = 5 \text{ V} \text{ with PW} < 10 \mu\text{s}$	250	350	_	mA
I _O _	Output Low Short-circuit Pulsed Current	V_O = 15 V, V_{IN} = 0 V with PW < 10 μs	500	650	-	
Vs	Allowable Negative V _S Pin Voltage for HIN Signal Propagation to HO		ı	-9.8	-7.0	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

DYNAMIC ELECTRICAL CHARACTERISTICS (V_{BIAS} (V_{CC} , V_{BS}) = 15.0 V, V_{S} = COM, C_{L} = 1000 pF and, T_{A} = 25°C, unless otherwise specified.)

Symbol	Characteristics	Test Condition	Min	Тур	Max	Unit
t _{on}	Turn-on Propagation Delay	V _S = 0 V	100	170	300	ns
t _{off}	Turn-off Propagation Delay	V _S = 0 V or 200 V (Note 4)	100	200	300	ns
t _r	Turn-on Rise Time		20	60	140	ns
t _f	Turn-off Fall Time		_	30	80	ns
MT	Delay Matching, HS & LS Turn-on/off		-	_	50	ns

^{4.} This parameter guaranteed by design.

TYPICAL CHARACTERISTICS

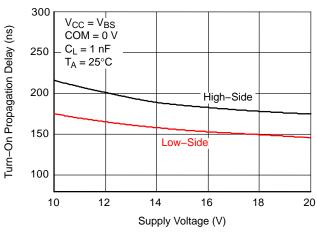


Figure 4. Turn-On Propagation Delay vs. Supply Voltage

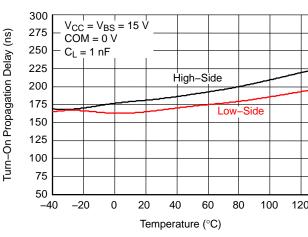


Figure 5. Turn-On Propagation Delay vs. Temperature

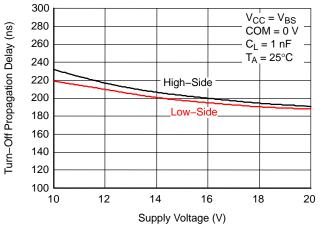


Figure 6. Turn-Off Propagation Delay vs. Supply Voltage

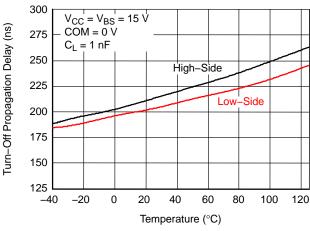


Figure 7. Turn-Off Propagation Delay vs. Temperature

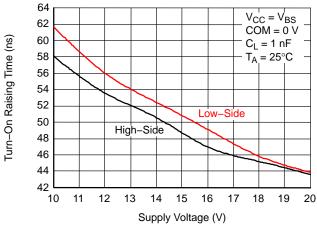


Figure 8. Turn-On Rising Time vs. Supply Voltage

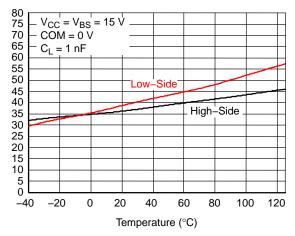
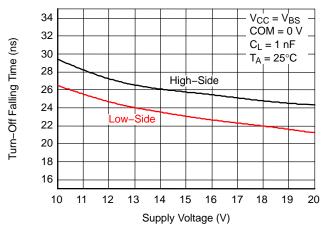


Figure 9. Turn-On Rising Time vs. Temperature

Furn-On Raising Time (ns)

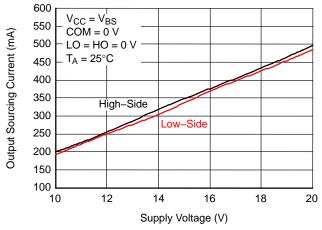
50



 $V_{CC} = V_{BS} = 15 \text{ V}$ COM = 0 V 45 Turn-Off Falling Time (ns) $C_L = 1 nF$ 40 35 High-Side 30 25 -Low-Side 20 15 10 40 60 80 100 -40 -20 20 Temperature (°C)

Figure 10. Turn-Off Falling Time vs. Supply Voltage

Figure 11. Turn-Off Falling Time vs. Temperature



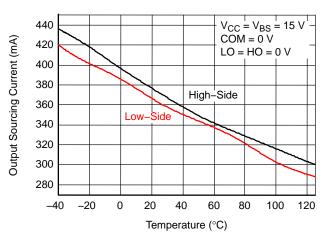
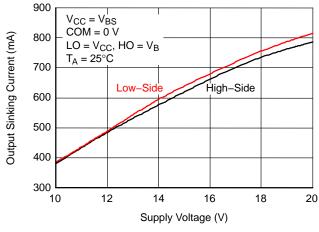


Figure 12. Output Sourcing Current vs. Supply Voltage

Figure 13. Output Sourcing Current vs. Temperature



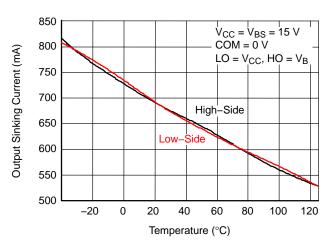
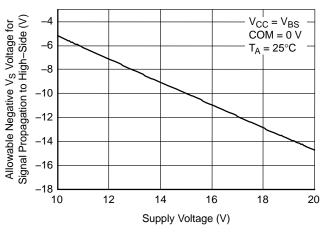


Figure 14. Output Sinking Current vs. Supply Voltage

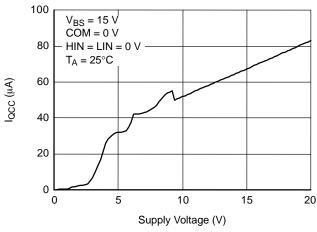
Figure 15. Output Sinking Current vs. Temperature



-9.0 Allowable Negative V_S Voltage for Signal Propagation to High–Side (V) $V_{CC} = V_{BS} = 15 \text{ V}$ COM = 0 V -9.2-9.4 -9.6-9.8 -10.0 -10.2 -10.4 -40 -20 20 40 60 80 100 120 Temperature (°C)

Figure 16. Allowable Negative V_S Voltage for Signal Propagation to High Side vs. Supply Voltage

Figure 17. Allowable Negative V_S Voltage for Signal Propagation to High Side vs. Temperature



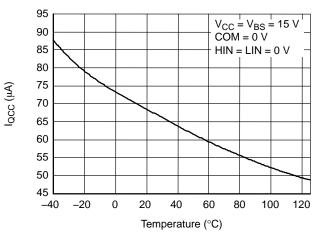
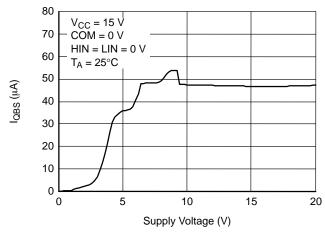


Figure 18. I_{QCC} vs. Supply Voltage

Figure 19. I_{QCC} vs. Temperature



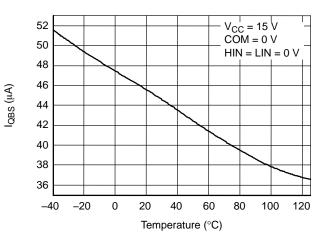


Figure 20. IQBS vs. Supply Voltage

Figure 21. I_{QBS} vs. Temperature

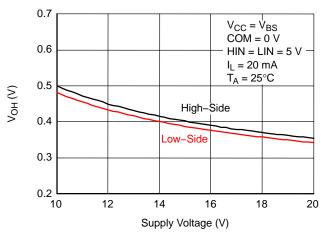


Figure 22. High-Level Output Voltage vs. Supply Voltage

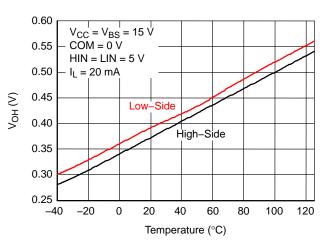


Figure 23. High-Level Output Voltage vs. Temperature

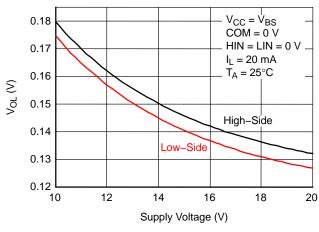


Figure 24. Low-Level Output Voltage vs. Supply Voltage

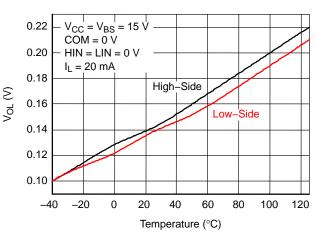


Figure 25. Low-Level Output Voltage vs. Temperature

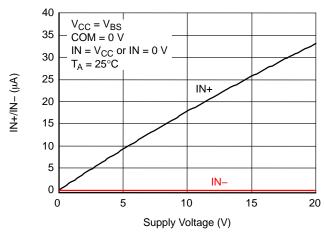


Figure 26. Input Bias Current vs. Supply Voltage

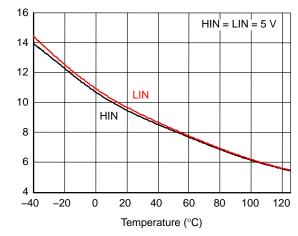


Figure 27. Input Bias Current vs. Temperature

(N+/IN- (μA)

TYPICAL CHARACTERISTICS (CONTINUED)

Input Logic Threshold Voltage (V)

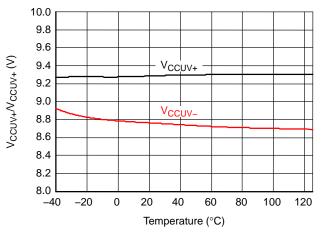


Figure 28. V_{CC} UVLO Threshold Voltage vs. Temperature

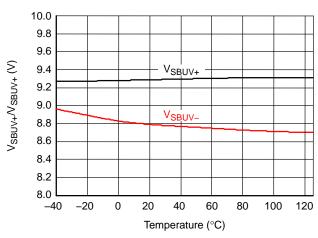


Figure 29. V_{BS} UVLO Threshold Voltage vs. Temperature

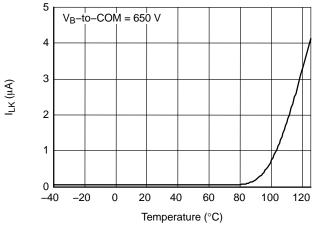


Figure 30. V_B to COM Leakage Current vs. Temperature

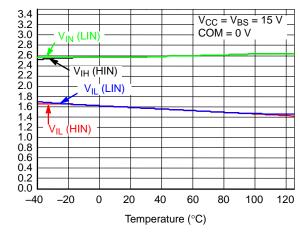


Figure 31. Input Logic Threshold Voltage vs. Temperature

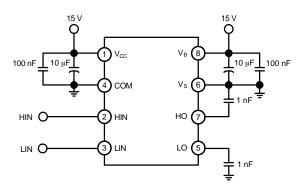


Figure 32. Switching Time Test Circuit

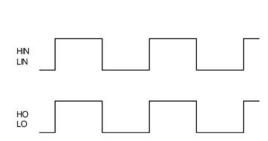


Figure 33. Input / Output Timing Diagram

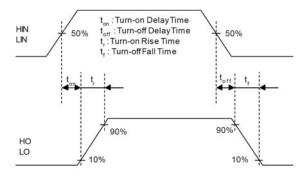


Figure 34. Switching Time Waveform Definition

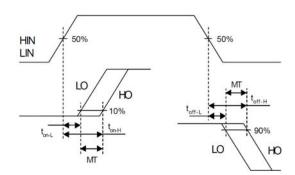


Figure 35. Delay Matching Waveform Definition

ORDERING INFORMATION

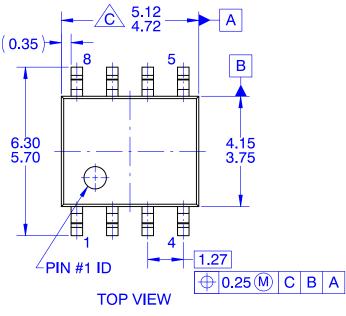
Part Number	Package	Operating Temperature Range	Shipping [†]
FAN7842MX (Note 5)	SOIC8 (8-SOP) (Pb-Free, Halide Free)	−40°C~125°C	3000 / Tape & Reel

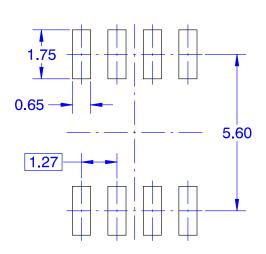
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{5.} These devices passed wave soldering test by JESD22A-111.

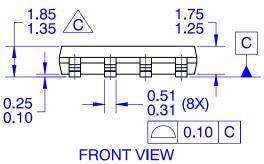
SOIC8 CASE 751EG ISSUE O

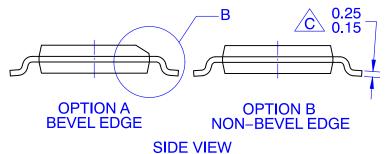
DATE 30 SEP 2016

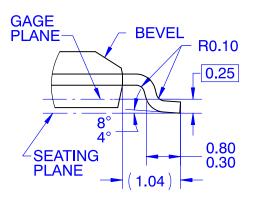




LAND PATTERN RECOMMENDATION







NOTES: UNLESS OTHERWISED SPECIFIED

- A. THIS PACKAGE CONFORMS TO JEDEC MS-012 VARIATION A EXCEPT WHERE NOTED.
- B. ALL DIMENSIONS ARE IN MILLIMETERS
- C OUT OF JEDEC STANDARD VALUE
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- E. LAND PATTERN AS PER IPC SOIC127P600X175–8M

DETAIL "B" SCALE 2:1

DOCUMENT NUMBER:	98AON13741G	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOIC8		PAGE 1 OF 1	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales